



DMN4031SSDQ

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C (Note 6)
40V	31mΩ @ V _{GS} = 10V	7.0A
	$50m\Omega @ V_{GS} = 4.5V$	5.8A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Backlighting
- Power-management functions
- DC-DC converters

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

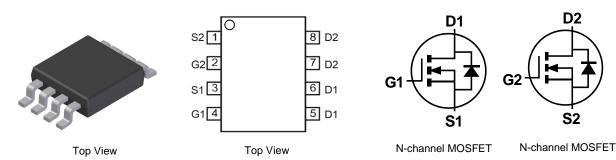
- Low On-Resistance
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN4031SSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

SO-8



Ordering Information (Note 4)

Part Number	Paakaga	Packing		
	Package	Qty. Carrier		
DMN4031SSDQ-13	SO-8	2,500	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

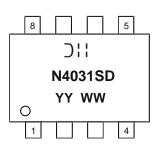
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



 $\begin{array}{l} \label{eq:2.1} \exists Manufacturer's Marking \\ N4031SD = Product Type Marking Code \\ YYWW or \overline{YY}WW= Date Code Marking \\ YY or \overline{YY} = Year (ex: 24 = 2024) \\ WW = Week (01 to 53) \end{array}$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage				Symbol	Value	Unit V
				V _{DSS}	40	
Gate-Source Voltage				Vgss	±20	V
Continuous Drain Current (Note 5)	VGS = 10V	Steady State	T _A = +25°C T _A = +70°C	lD	5.2 4.1	A
Continuous Drain Current (Note 5)	$V_{GS} = 4.5V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	4.3 3.4	A
Continuous Drain Current (Note 6)	V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	lo	7.0 5.6	A
Continuous Drain Current (Note 6)	V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	lD	5.8 4.7	A
Pulsed Drain Current (Note 7)				I _{DM}	40	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.42	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	88	°C/W
Total Power Dissipation (Note 6)	PD	2.6	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	Reja	48	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

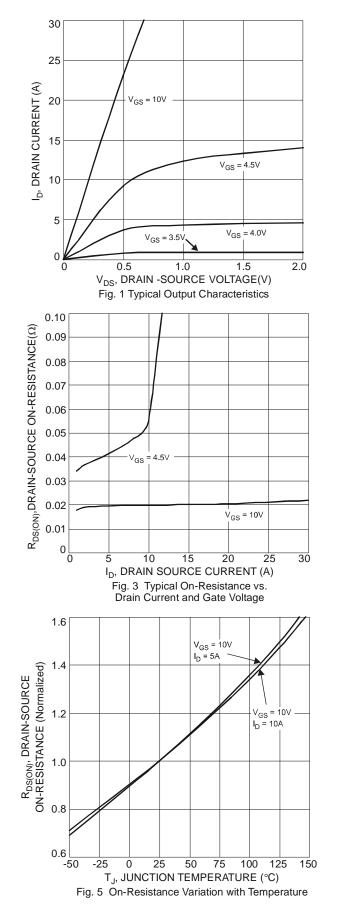
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

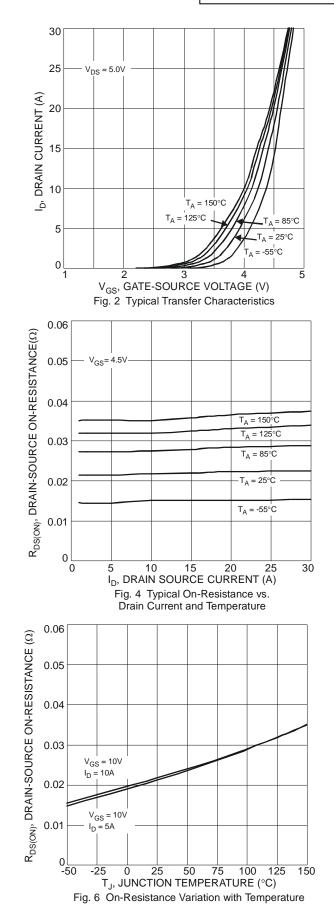
Characteristic	Symbol	Min	Turn	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Symbol	IVIIII	Тур	WIdx	Unit	Test condition	
Drain-Source Breakdown Voltage	BVDSS	40	_	_	V	$V_{GS} = 0V, I_{D} = 10mA$	
Zero Gate Voltage Drain Current		_	_	1	μA	$V_{DS} = 40V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(th)	1.6	2.4	3.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
On-State Drain Current	ID(ON)	20	—	_	А	Vgs = 10V, Vps = 5A	
Statia Dusia Course On Desistance		_	19	31		Vgs = 10V, ID = 6A	
Static Drain-Source On-Resistance	Rds(on)	_	44	50	mΩ	Vgs = 4.5V, Ip = 5A	
Forward Transfer Admittance	Y _{fs}		11	—	S	$V_{DS} = 5V, I_D = 6A$	
Diode Forward Voltage	Vsd	_	0.74	1.0	V	VGS = 0V, IS = 1A	
DYNAMIC CHARACTERISTICS (Note 9)	·						
Input Capacitance	Ciss		945	_	pF		
Output Capacitance	Coss		69	—	pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	58	_	pF	1 = 1.00012	
Gate Resistance	Rg		1.45	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	8.4	-	nC	$V_{GS} = 4.5V, V_{DS} = 20V,$ ID = 12A	
Total Gate Charge (V _{GS} = 10V)	Qg	_	18.6	_	nC		
Gate-Source Charge	Q _{gs}	_	3.3	_	nC	$V_{GS} = 10V, V_{DS} = 20V, I_D = 12A$	
Gate-Drain Charge	Qgd	_	2.2	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	6.4	—	ns		
Turn-On Rise Time	tR		9.7	_	ns	$V_{GS} = 10V, V_{DS} = 20V,$ $R_{L} = 1.6\Omega, R_{G} = 3\Omega$	
Turn-Off Delay Time	tD(OFF)		19.8	_	ns		
Turn-Off Fall Time	t _F		3.1	_	ns		

 Device mounted on FR-4 PCB, with minimum recommended pad layout. The value in any given application depends on user's specific board design.
Device mounted on 1" x 1" FR-4 PCB with high coverage 1 oz. Copper, single sided.
Repetitive rating, pulse width limited by junction temperature. Notes:

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. No subject to production testing.









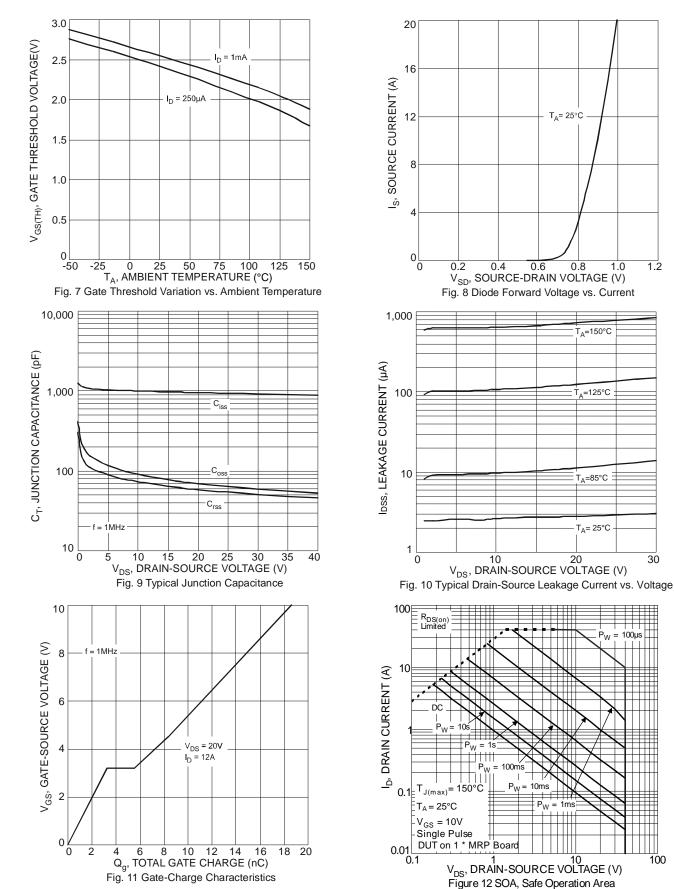
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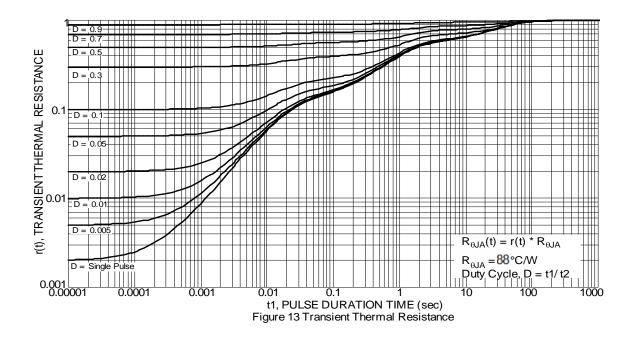
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DMN4031SSDQ Document number: DS37995 Rev. 5 - 2

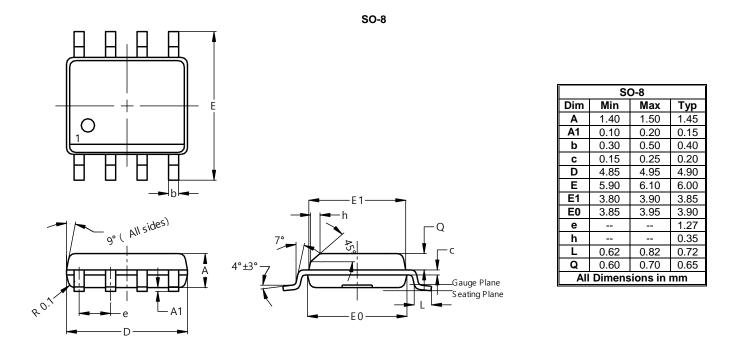






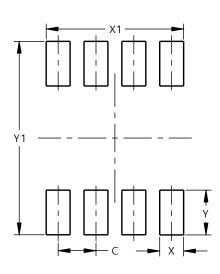
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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